

## P Substrate High Power TVS Diode

### Features

- ◆ 7000Watts peak pulse power ( $t_p = 8/20\mu s$ )
- ◆ Uni-directional configurations
- ◆ Solid-state silicon-avalanche technology
- ◆ Capacitance: 660pF typical
- ◆ Low clamping voltage
- ◆ Low leakage current
- ◆ AEC-Q101 qualified (Automotive grade with suffix "Q".)
- ◆ Expsemi electronics
- ◆ Complies with following standards:
  - IEC 61000-4-2 (ESD) immunity test

Air discharge:  $\pm 30KV$

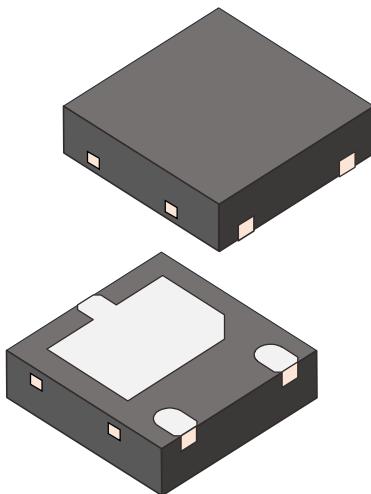
Contact discharge:  $\pm 30KV$

- IEC61000-4-4 (EFT) 40A (5/50ns)
- IEC61000-4-5 (Lightning) 200A (8/20us)

**DFN2020P3**

DFN2×2-3L

2mm×2mm×0.5mm



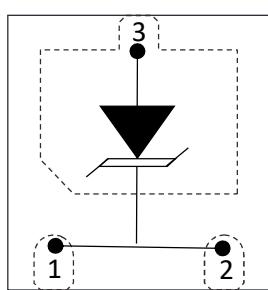
### Applications

- ◆ Cell phone handsets and accessories
- ◆ Personal digital assistants (PDA's)
- ◆ Notebooks, desktops, and servers
- ◆ Portable instrumentation
- ◆ Cordless phones
- ◆ Digital cameras

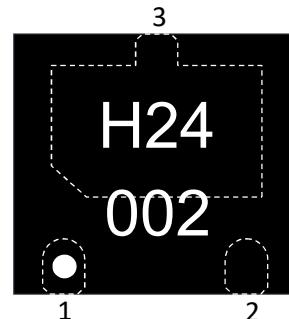
### Mechanical Data

- ◆ Package: DFN2020P3
- ◆ UL Flammability Classification Rating 94V-0
- ◆ Packaging: Tape and Reel
- ◆ RoHS/WEEE Compliant

### Schematic & PIN Configuration



### Marking



## Absolute Maximum Ratings

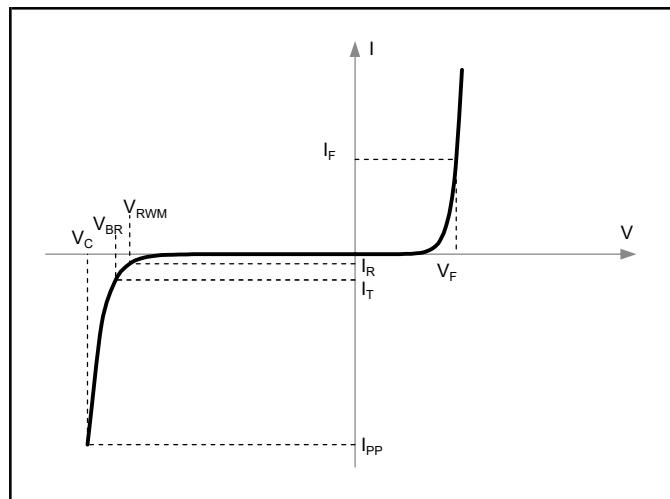
Parameter	Symbol	Value	Units
Reverse Working Voltage	$V_{RWM}$	24	V
Peak Pulse Power ( $tp=8/20\mu s$ )	$P_{PP}$	7000	W
Peak Pulse Current ( $tp=8/20\mu s$ )	$I_{PP}$	200	A
ESD per IEC 61000-4-2 (Air)	$V_{ESD-Air}$	30	KV
ESD per IEC 61000-4-2 (Contact)	$V_{ESD-Contact}$	30	KV
Lead Soldering Temperature (10s)	$T_L$	260	°C
Operating Junction Temperature Range	$T_J$	-55 to 125	°C
Storage Temperature Range	$T_{STG}$	-55 to 150	°C

## Electrical Characteristics

Parameter	Symbol	Conditions	Min	Typ	Max	Units
Breakdown Voltage	$V_{BR}$	$I_T = 1mA$	26			V
Reverse Leakage Current	$I_R$	$V_{RWM} = 24V$			1	uA
Clamping Voltage	$V_C$	$I_{PP} = 100A, tp=8/20\mu s$			30	V
		$I_{PP} = 200A, tp=8/20\mu s$			35	V
Junction Capacitance	$C_J$	$V_{DC} = 0V, f=1MHz$		660		pF

## Electrical Parameters

Symbol	Definition
$I_{PP}$	Peak Pulse Current
$V_C$	Clamping Voltage
$V_{RWM}$	Reverse Working Voltage
$I_R$	Reverse Leakage Current
$V_{BR}$	Breakdown Voltage
$I_T$	Test Current
$V_F$	Forward Voltage
$I_F$	Forward Current



## Typical Characteristics

Fig.1 - Peak Pulse Power Rating

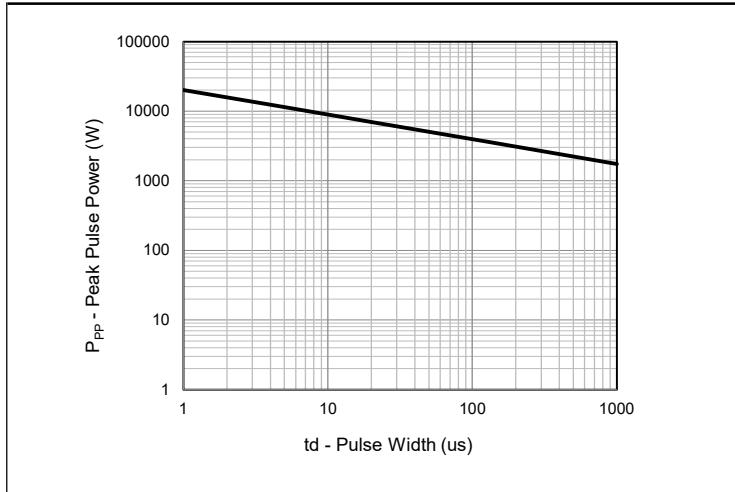


Fig.2 - Pulse Derating Curve

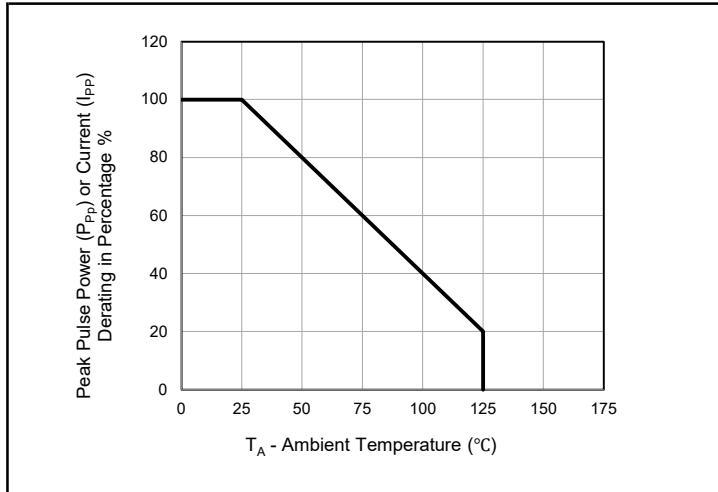


Fig.3 - 8/20us Pulse Waveform

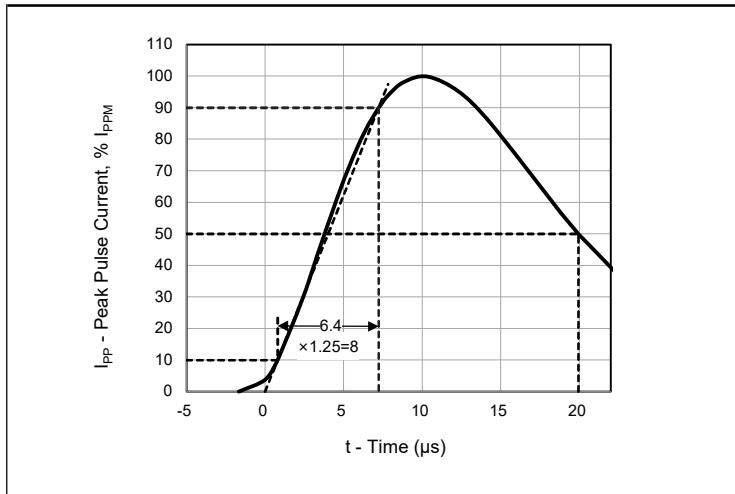


Fig.4 - Typical Clamping Voltage

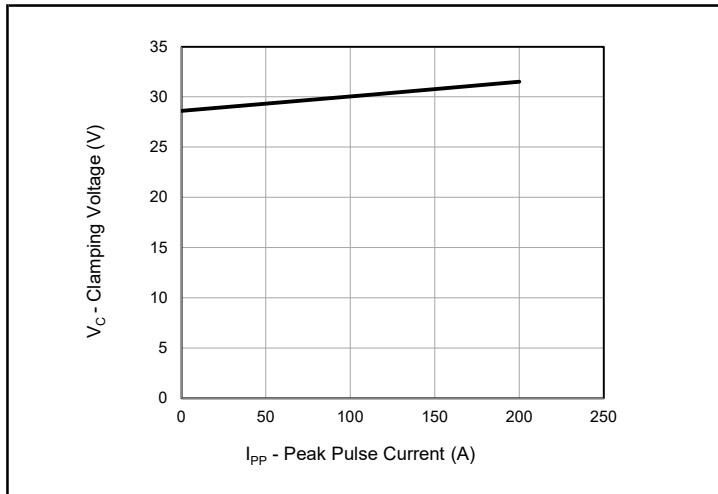


Fig.5 - ESD Pulse Waveform (IEC61000-4-2)

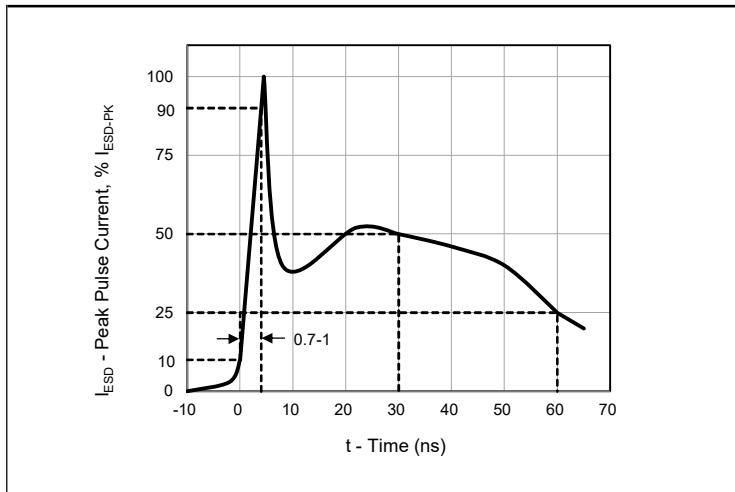
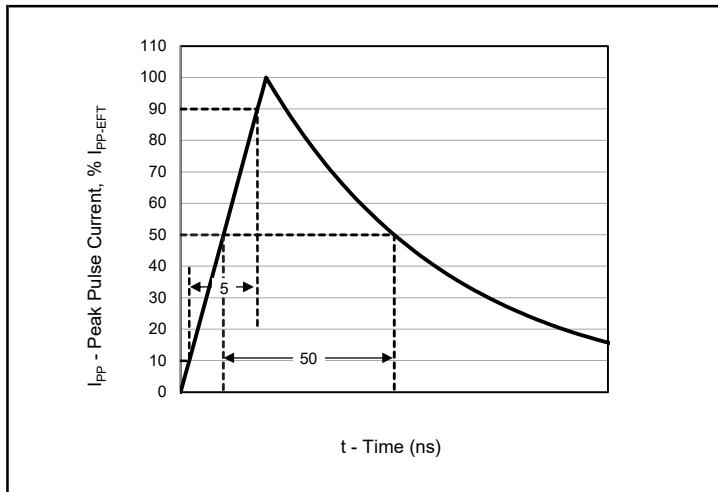
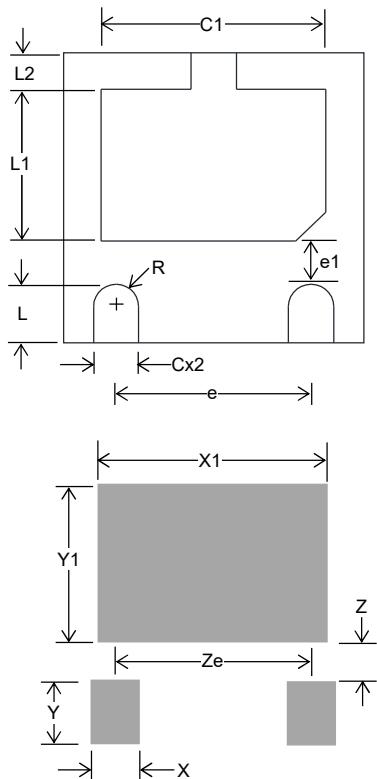
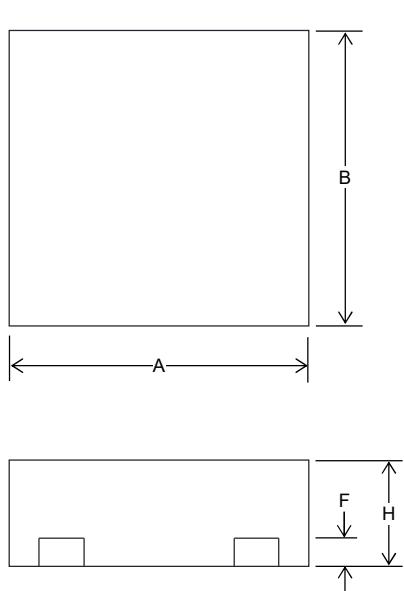


Fig.6 - 5/50ns EFT Waveform (IEC61000-4-4)



## Outline Drawing



DFN2020P3			
SYMBOL	Millimeters		
	MIN	NOM	MAX
A	1.95	2	2.05
B	1.95	2	2.05
C	0.25	0.3	0.35
F	0.17	0.2	0.23
G		0.02	0.05
H	0.48	0.53	0.58
L	0.35	0.4	0.45
e		1.3	
C1	1.4	1.5	1.6
L1	1	1.05	1.1
L2	0.2	0.25	0.3
e1		0.25	
R	0.13		
X		0.4	
Y		0.5	
Z		0.25	
Ze		1.3	

## Ordering Information

Order Code	Package	Base Quantity	Delivery Mode
EP2401HSP	DFN2020P3	3000 PCS/Reel	Tape and Reel